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### What is "[Embedded - Microcontrollers](#)"?

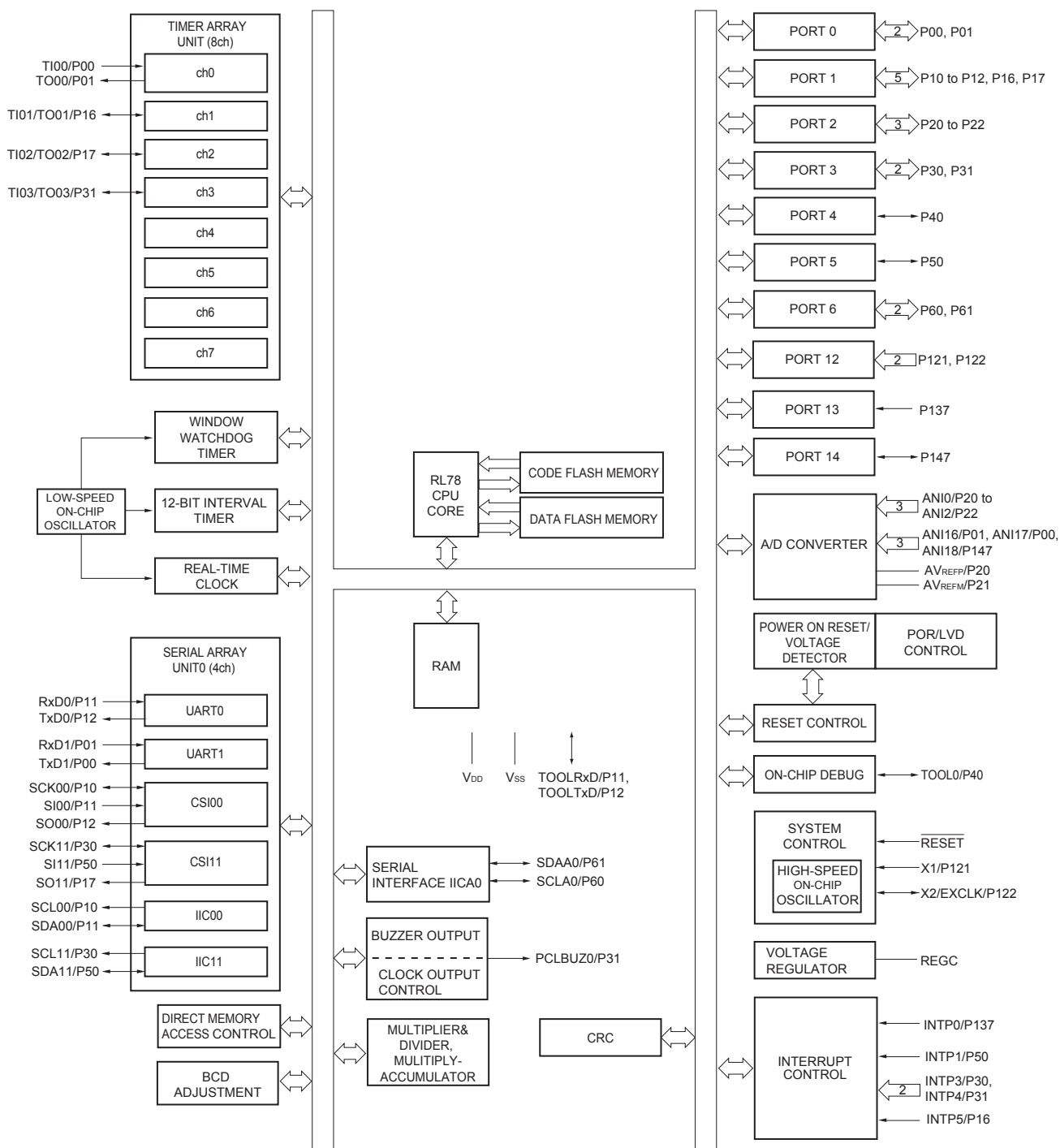
"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

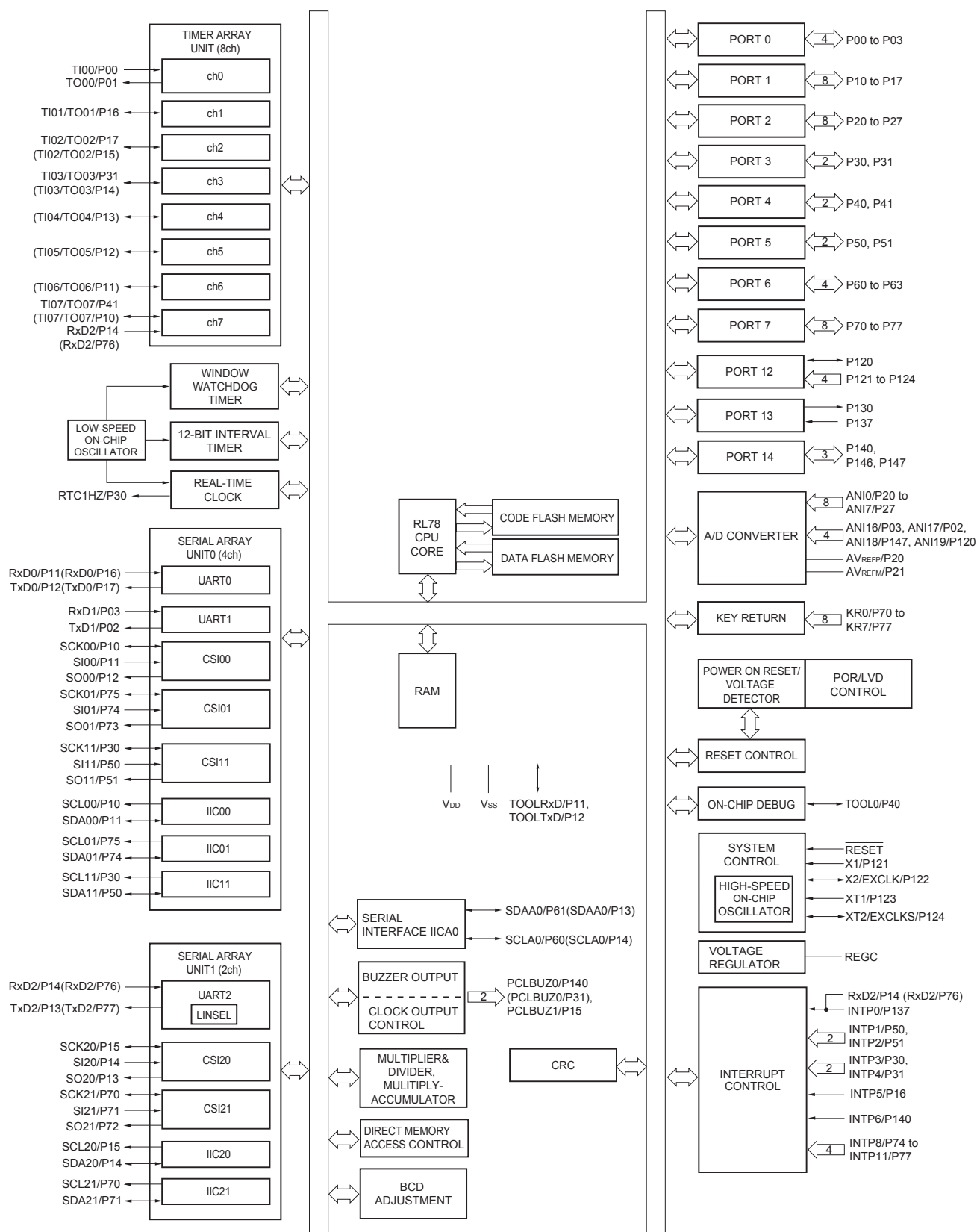
#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	32MHz
Connectivity	CSI, I <sup>2</sup> C, LINbus, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	34
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.6V ~ 5.5V
Data Converters	A/D 10x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-WFQFN Exposed Pad
Supplier Device Package	48-HWQFN (7x7)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100geana-u0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f100geana-u0</a>

## 1.5.2 24-pin products

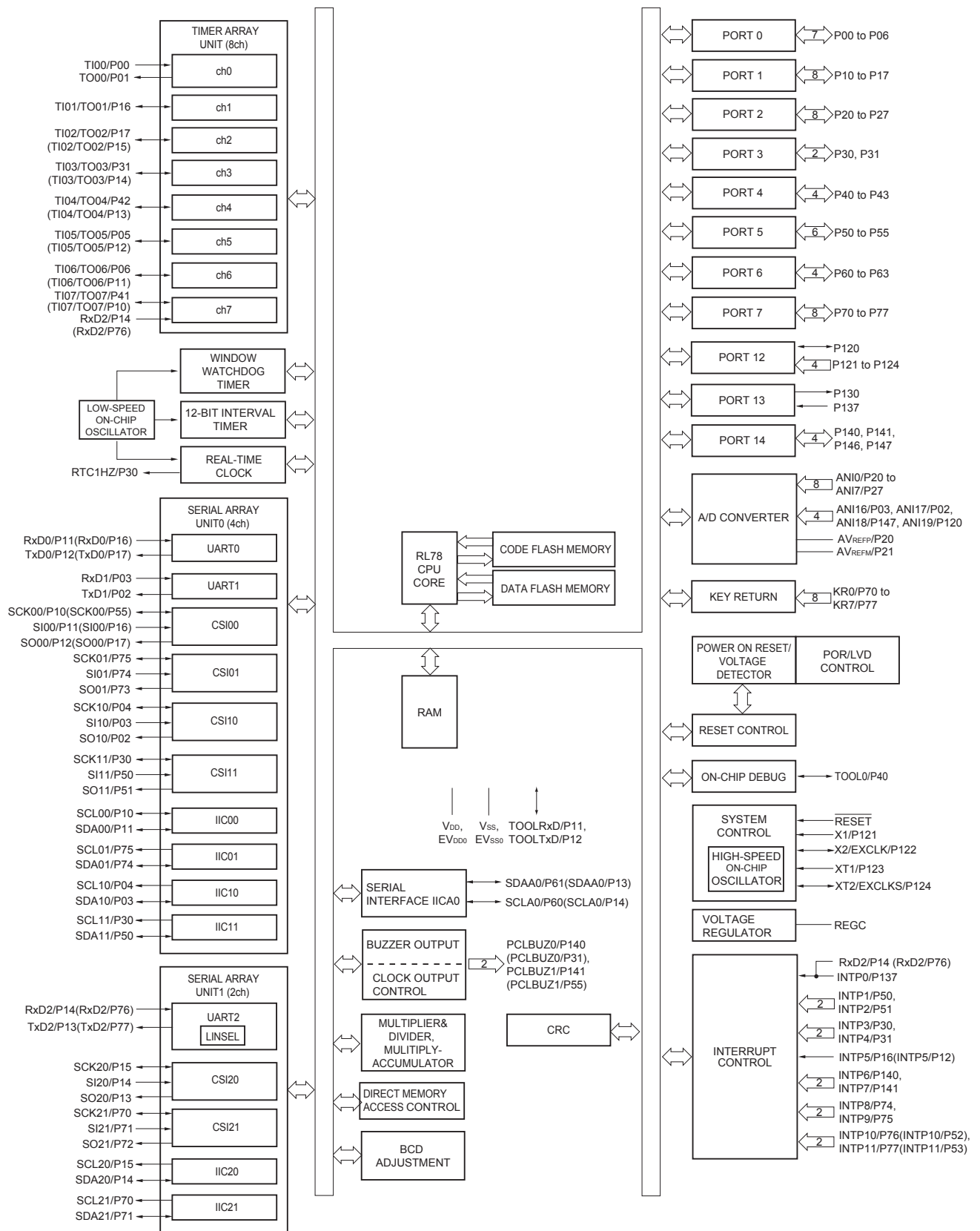


## 1.5.10 52-pin products



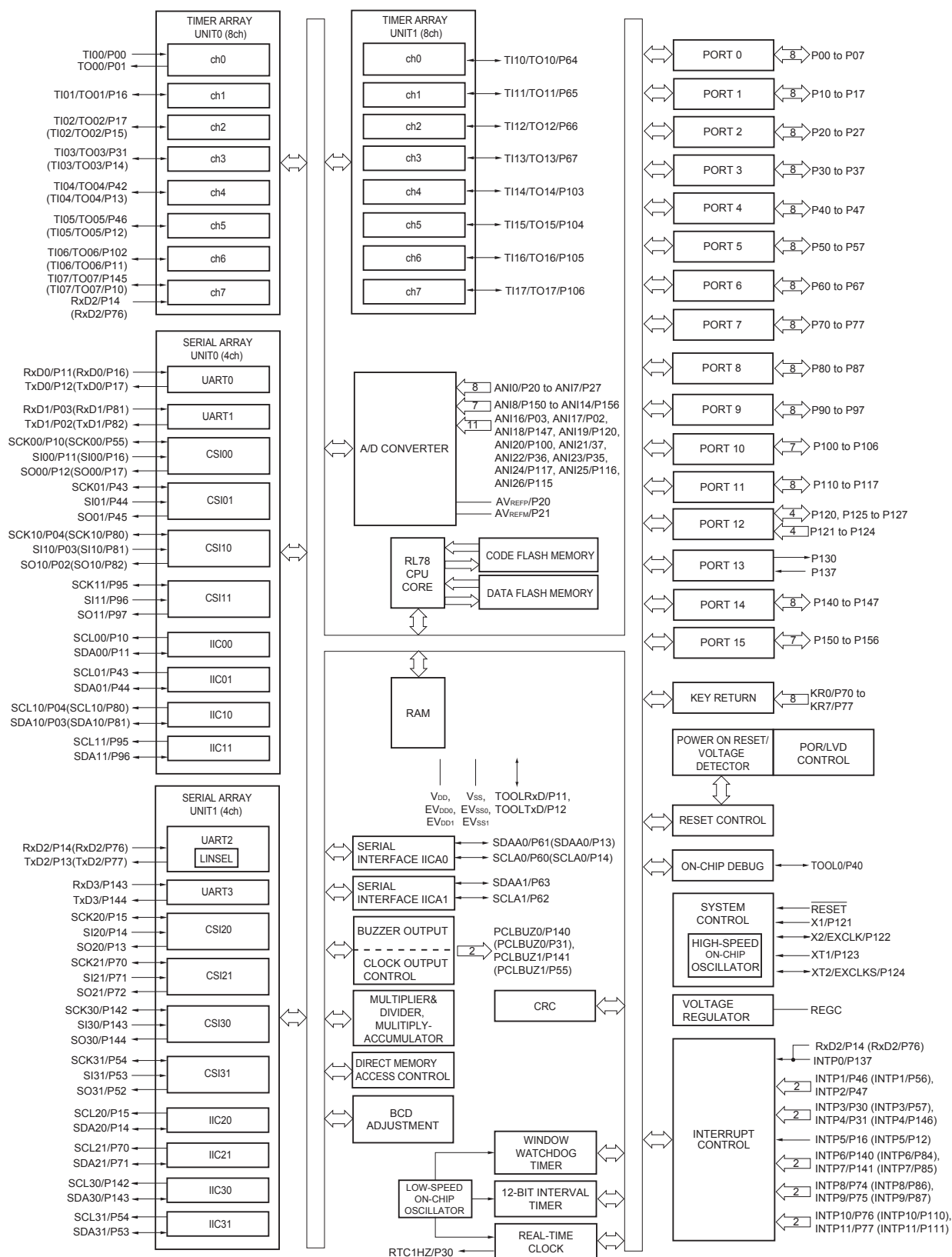
**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

## 1.5.11 64-pin products



**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

## 1.5.14 128-pin products



**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). Refer to **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)** in the RL78/G13 User's Manual.

## 2.3.2 Supply current characteristics

## (1) Flash ROM: 16 to 64 KB of 20- to 64-pin products

(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD0</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = 0 V) (1/2)

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit		
Supply current <small>Note 1</small>	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode <small>Note 5</small>	f <sub>IH</sub> = 32 MHz <small>Note 3</small>	Basic operation	V <sub>DD</sub> = 5.0 V		2.1		mA	
						V <sub>DD</sub> = 3.0 V		2.1		mA	
					Normal operation	V <sub>DD</sub> = 5.0 V		4.6	7.0	mA	
						V <sub>DD</sub> = 3.0 V		4.6	7.0	mA	
					f <sub>IH</sub> = 24 MHz <small>Note 3</small>	Normal operation	V <sub>DD</sub> = 5.0 V		3.7	5.5	mA
							V <sub>DD</sub> = 3.0 V		3.7	5.5	mA
				f <sub>IH</sub> = 16 MHz <small>Note 3</small>	Normal operation	V <sub>DD</sub> = 5.0 V		2.7	4.0	mA	
						V <sub>DD</sub> = 3.0 V		2.7	4.0	mA	
				LS (low-speed main) mode <small>Note 5</small>	f <sub>IH</sub> = 8 MHz <small>Note 3</small>	Normal operation	V <sub>DD</sub> = 3.0 V		1.2	1.8	mA
							V <sub>DD</sub> = 2.0 V		1.2	1.8	mA
				LV (low-voltage main) mode <small>Note 5</small>	f <sub>IH</sub> = 4 MHz <small>Note 3</small>	Normal operation	V <sub>DD</sub> = 3.0 V		1.2	1.7	mA
							V <sub>DD</sub> = 2.0 V		1.2	1.7	mA
			HS (high-speed main) mode <small>Note 5</small>	f <sub>MX</sub> = 20 MHz <small>Note 2</small> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.0	4.6	mA	
						Resonator connection		3.2	4.8	mA	
					f <sub>MX</sub> = 20 MHz <small>Note 2</small> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		3.0	4.6	mA
							Resonator connection		3.2	4.8	mA
					f <sub>MX</sub> = 10 MHz <small>Note 2</small> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		1.9	2.7	mA
							Resonator connection		1.9	2.7	mA
				f <sub>MX</sub> = 10 MHz <small>Note 2</small> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.9	2.7	mA	
						Resonator connection		1.9	2.7	mA	
				LS (low-speed main) mode <small>Note 5</small>	f <sub>MX</sub> = 8 MHz <small>Note 2</small> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.1	1.7	mA
							Resonator connection		1.1	1.7	mA
					f <sub>MX</sub> = 8 MHz <small>Note 2</small> , V <sub>DD</sub> = 2.0 V	Normal operation	Square wave input		1.1	1.7	mA
							Resonator connection		1.1	1.7	mA
		Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <small>Note 4</small> T <sub>A</sub> = -40°C	Normal operation	Square wave input		4.1	4.9	μA		
					Resonator connection		4.2	5.0	μA		
			f <sub>SUB</sub> = 32.768 kHz <small>Note 4</small> T <sub>A</sub> = +25°C	Normal operation	Square wave input		4.1	4.9	μA		
					Resonator connection		4.2	5.0	μA		
			f <sub>SUB</sub> = 32.768 kHz <small>Note 4</small> T <sub>A</sub> = +50°C	Normal operation	Square wave input		4.2	5.5	μA		
					Resonator connection		4.3	5.6	μA		
			f <sub>SUB</sub> = 32.768 kHz <small>Note 4</small> T <sub>A</sub> = +70°C	Normal operation	Square wave input		4.3	6.3	μA		
					Resonator connection		4.4	6.4	μA		
			f <sub>SUB</sub> = 32.768 kHz <small>Note 4</small> T <sub>A</sub> = +85°C	Normal operation	Square wave input		4.6	7.7	μA		
					Resonator connection		4.7	7.8	μA		

(Notes and Remarks are listed on the next page.)

**(3) 128-pin products, and flash ROM: 384 to 512 KB of 44- to 100-pin products****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ E<sub>VDD0</sub> = E<sub>VDD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = E<sub>VSS0</sub> = E<sub>VSS1</sub> = 0 V) (1/2)**

Parameter	Symbol	Conditions				MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS (high-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 32 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		2.6	mA
						V <sub>DD</sub> = 3.0 V		2.6	mA
					Normal operation	V <sub>DD</sub> = 5.0 V		6.1	mA
						V <sub>DD</sub> = 3.0 V		6.1	mA
				f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		4.8	mA
						V <sub>DD</sub> = 3.0 V		4.8	mA
				f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 5.0 V		3.5	mA
						V <sub>DD</sub> = 3.0 V		3.5	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 8 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.5	mA
						V <sub>DD</sub> = 2.0 V		1.5	mA
			LV (low-voltage main) mode <sup>Note 5</sup>	f <sub>IH</sub> = 4 MHz <sup>Note 3</sup>	Normal operation	V <sub>DD</sub> = 3.0 V		1.5	mA
						V <sub>DD</sub> = 2.0 V		1.5	mA
			HS (high-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		3.9	mA
						Resonator connection		4.1	mA
				f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		3.9	mA
						Resonator connection		4.1	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Normal operation	Square wave input		2.5	mA
						Resonator connection		2.5	mA
				f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		2.5	mA
						Resonator connection		2.5	mA
			LS (low-speed main) mode <sup>Note 5</sup>	f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Normal operation	Square wave input		1.4	mA
						Resonator connection		1.4	mA
				f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 2.0 V	Normal operation	Square wave input		1.4	mA
						Resonator connection		1.4	mA
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = -40°C	Normal operation	Square wave input		5.4	μA
						Resonator connection		5.5	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +25°C	Normal operation	Square wave input		5.5	μA
						Resonator connection		5.6	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +50°C	Normal operation	Square wave input		5.6	μA
						Resonator connection		5.7	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +70°C	Normal operation	Square wave input		5.9	μA
						Resonator connection		6.0	μA
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 4</sup> T <sub>A</sub> = +85°C	Normal operation	Square wave input		6.6	μA
						Resonator connection		6.7	μA

(Notes and Remarks are listed on the next page.)

**(3) 128-pin products, and flash ROM: 384 to 512 KB of 44- to 100-pin products****(T<sub>A</sub> = -40 to +85°C, 1.6 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V) (2/2)**

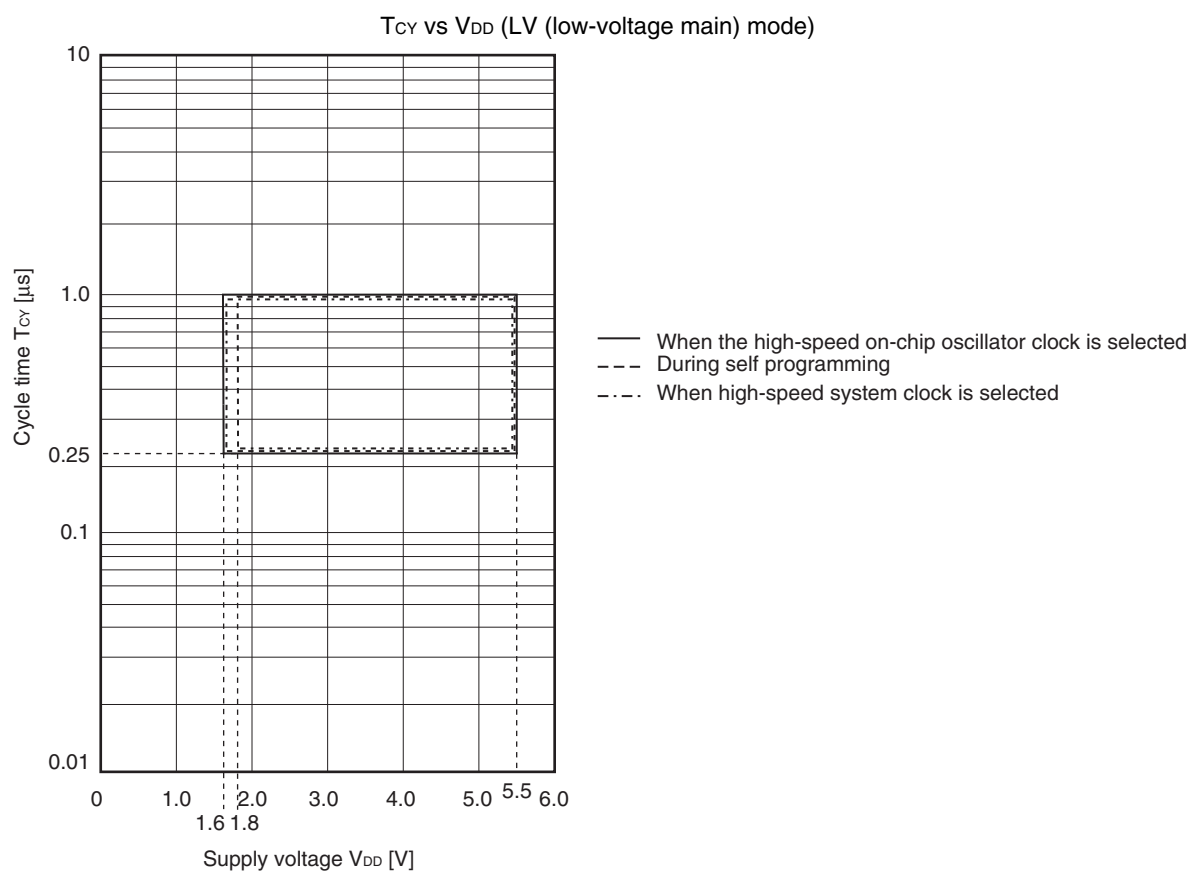
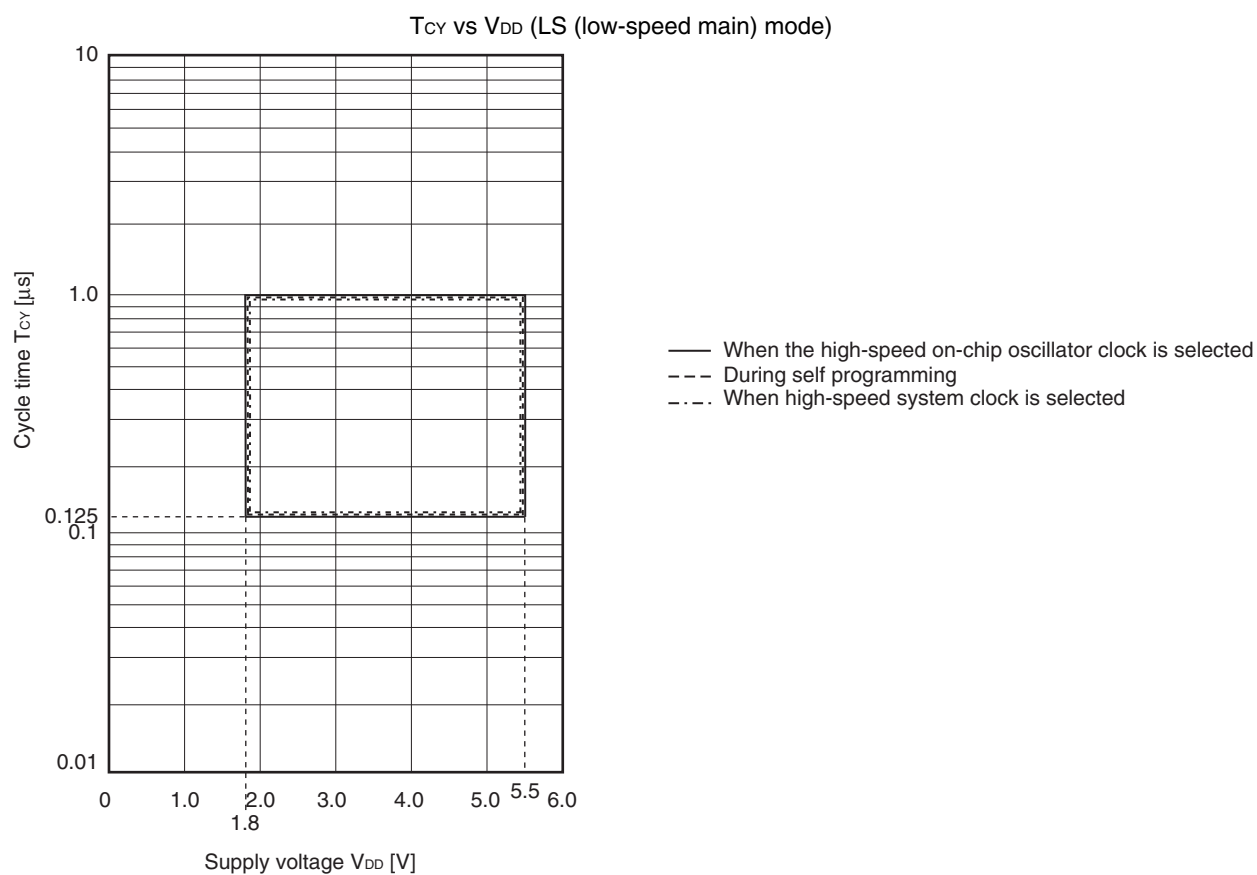
Parameter	Symbol				Conditions	MIN.	TYP.	MAX.	Unit	
Supply current Note 1	I <sub>DD2</sub> Note 2	HALT mode	HS (high-speed main) mode Note 7	f <sub>IH</sub> = 32 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.62	1.89	mA	
					V <sub>DD</sub> = 3.0 V		0.62	1.89	mA	
				f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.50	1.48	mA	
					V <sub>DD</sub> = 3.0 V		0.50	1.48	mA	
				f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V		0.44	1.12	mA	
					V <sub>DD</sub> = 3.0 V		0.44	1.12	mA	
			LS (low-speed main) mode Note 7	f <sub>IH</sub> = 8 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 3.0 V		290	620	μA	
					V <sub>DD</sub> = 2.0 V		290	620	μA	
			LV (low-voltage main) mode Note 7	f <sub>IH</sub> = 4 MHz <sup>Note 4</sup>	V <sub>DD</sub> = 3.0 V		460	700	μA	
					V <sub>DD</sub> = 2.0 V		460	700	μA	
			HS (high-speed main) mode Note 7	f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		0.31	1.14	mA	
					Resonator connection		0.48	1.34	mA	
				f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		0.31	1.14	mA	
					Resonator connection		0.48	1.34	mA	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		0.21	0.68	mA	
					Resonator connection		0.28	0.76	mA	
				f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		0.21	0.68	mA	
					Resonator connection		0.28	0.76	mA	
			LS (low-speed main) mode Note 7	f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		110	390	μA	
					Resonator connection		160	450	μA	
				f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> , V <sub>DD</sub> = 2.0 V	Square wave input		110	390	μA	
					Resonator connection		160	450	μA	
			Subsystem clock operation	f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = −40°C	Square wave input		0.31	0.66	μA	
					Resonator connection		0.50	0.85	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +25°C	Square wave input		0.38	0.66	μA	
					Resonator connection		0.57	0.85	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +50°C	Square wave input		0.47	3.49	μA	
					Resonator connection		0.66	3.68	μA	
				f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +70°C	Square wave input		0.80	6.10	μA	
					Resonator connection		0.99	6.29	μA	
			f <sub>SUB</sub> = 32.768 kHz <sup>Note 5</sup> T <sub>A</sub> = +85°C	Square wave input		1.52	10.46	μA		
				Resonator connection		1.71	10.65	μA		
	I <sub>DD3</sub> <sup>Note 6</sup>	STOP mode <sup>Note 8</sup>	T <sub>A</sub> = −40°C					0.19	0.54	μA
			T <sub>A</sub> = +25°C					0.26	0.54	μA
			T <sub>A</sub> = +50°C					0.35	3.37	μA
			T <sub>A</sub> = +70°C					0.68	5.98	μA
			T <sub>A</sub> = +85°C					1.40	10.34	μA

(Notes and Remarks are listed on the next page.)



6. Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$  or  $I_{DD2}$  and  $I_{ADC}$  when the A/D converter operates in an operation mode or the HALT mode.
7. Current flowing only to the LVD circuit. The supply current of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit is in operation.
8. Current flowing only during data flash rewrite.
9. Current flowing only during self programming.
10. For shift time to the SNOOZE mode, see **18.3.3 SNOOZE mode**.

- Remarks**
1.  $f_{IL}$ : Low-speed on-chip oscillator clock frequency
  2.  $f_{SUB}$ : Subsystem clock frequency (XT1 clock oscillation frequency)
  3.  $f_{CLK}$ : CPU/peripheral hardware clock frequency
  4. Temperature condition of the TYP. value is  $T_A = 25^{\circ}\text{C}$



**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode) (1/2)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions		HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit	
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
Transfer rate		Reception	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V			f <sub>MCK</sub> /6 Note 1		f <sub>MCK</sub> /6 Note 1		f <sub>MCK</sub> /6 Note 1	bps
						5.3		1.3		0.6	Mbps
			Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> <sup>Note 4</sup>								
						5.3		1.3		0.6	Mbps
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V			f <sub>MCK</sub> /6 Note 1		f <sub>MCK</sub> /6 Note 1		f <sub>MCK</sub> /6 Note 1	bps
						5.3		1.3		0.6	Mbps
1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V			f <sub>MCK</sub> /6 Notes 1 to 3		f <sub>MCK</sub> /6 Notes 1, 2		f <sub>MCK</sub> /6 Notes 1, 2	bps			
			5.3		1.3		0.6	Mbps			
Theoretical value of the maximum transfer rate f <sub>MCK</sub> = f <sub>CLK</sub> <sup>Note 4</sup>											

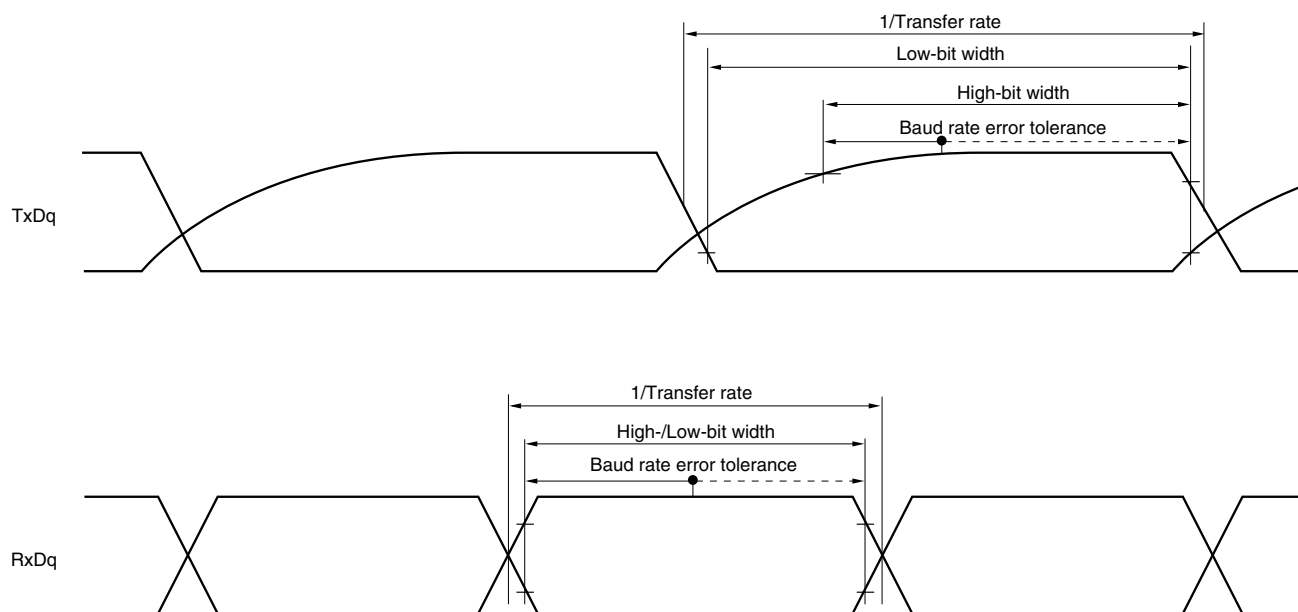
**Notes 1.** Transfer rate in the SNOOZE mode is 4800 bps only.**2.** Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.**3.** The following conditions are required for low voltage interface when EV<sub>DD0</sub> < V<sub>DD</sub>.2.4 V ≤ EV<sub>DD0</sub> < 2.7 V : MAX. 2.6 Mbps1.8 V ≤ EV<sub>DD0</sub> < 2.4 V : MAX. 1.3 Mbps**4.** The maximum operating frequencies of the CPU/peripheral hardware clock (f<sub>CLK</sub>) are:HS (high-speed main) mode: 32 MHz (2.7 V ≤ V<sub>DD</sub> ≤ 5.5 V)16 MHz (2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V)LS (low-speed main) mode: 8 MHz (1.8 V ≤ V<sub>DD</sub> ≤ 5.5 V)LV (low-voltage main) mode: 4 MHz (1.6 V ≤ V<sub>DD</sub> ≤ 5.5 V)

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

**Remarks 1.** V<sub>b</sub>[V]: Communication line voltage**2.** q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)**3.** f<sub>MCK</sub>: Serial array unit operation clock frequency

(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))

**4.** UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

**UART mode bit width (during communication at different potential) (reference)**

- Remarks**
1.  $R_b[\Omega]$ : Communication line (TxDq) pull-up resistance,  
 $C_b[\text{F}]$ : Communication line (TxDq) load capacitance,  $V_b[\text{V}]$ : Communication line voltage
  2. q: UART number (q = 0 to 3), g: PIM and POM number (g = 0, 1, 8, 14)
  3.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn).  
 m: Unit number, n: Channel number (mn = 00 to 03, 10 to 13))
  4. UART2 cannot communicate at different potential when bit 1 (PIOR1) of peripheral I/O redirection register (PIOR) is 1.

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output)**  
**(2/3)****(T<sub>A</sub> = -40 to +85°C, 1.8 V ≤ EV<sub>DD0</sub> = EV<sub>DD1</sub> ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = EV<sub>SS0</sub> = EV<sub>SS1</sub> = 0 V)**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		LV (low-voltage main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↑) <sup>Note 1</sup>	t <sub>SIK1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	81		479		479		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	177		479		479		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	479		479		479		ns
Slp hold time (from SCKp↑) <sup>Note 1</sup>	t <sub>KSH1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ	19		19		19		ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ	19		19		19		ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ	19		19		19		ns
Delay time from SCKp↓ to SOp output <sup>Note 1</sup>	t <sub>KSO1</sub>	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V, 2.7 V ≤ V <sub>b</sub> ≤ 4.0 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 1.4 kΩ		100		100		100	ns
		2.7 V ≤ EV <sub>DD0</sub> < 4.0 V, 2.3 V ≤ V <sub>b</sub> ≤ 2.7 V, C <sub>b</sub> = 30 pF, R <sub>b</sub> = 2.7 kΩ		195		195		195	ns
		1.8 V ≤ EV <sub>DD0</sub> < 3.3 V, 1.6 V ≤ V <sub>b</sub> ≤ 2.0 V <sup>Note 2</sup> , C <sub>b</sub> = 30 pF, R <sub>b</sub> = 5.5 kΩ		483		483		483	ns

- Notes**
1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.
  2. Use it with EV<sub>DD0</sub> ≥ V<sub>b</sub>.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output (V<sub>DD</sub> tolerance (When 20- to 52-pin products)/EV<sub>DD</sub> tolerance (When 64- to 128-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the page after the next page.)

**(3) Peripheral Functions (Common to all products)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}0} = \text{EV}_{\text{DD}1} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}0} = \text{EV}_{\text{SS}1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed on-chip oscillator operating current	$I_{\text{FIL}}$ Note 1				0.20		$\mu\text{A}$
RTC operating current	$I_{\text{RTC}}$ Notes 1, 2, 3				0.02		$\mu\text{A}$
12-bit interval timer operating current	$I_{\text{IT}}$ Notes 1, 2, 4				0.02		$\mu\text{A}$
Watchdog timer operating current	$I_{\text{WDT}}$ Notes 1, 2, 5	$f_{\text{IL}} = 15\text{ kHz}$			0.22		$\mu\text{A}$
A/D converter operating current	$I_{\text{ADC}}$ Notes 1, 6	When conversion at maximum speed	Normal mode, $\text{AV}_{\text{REFP}} = \text{V}_{\text{DD}} = 5.0\text{ V}$		1.3	1.7	$\text{mA}$
			Low voltage mode, $\text{AV}_{\text{REFP}} = \text{V}_{\text{DD}} = 3.0\text{ V}$		0.5	0.7	$\text{mA}$
A/D converter reference voltage current	$I_{\text{ADREF}}$ Note 1				75.0		$\mu\text{A}$
Temperature sensor operating current	$I_{\text{TMPS}}$ Note 1				75.0		$\mu\text{A}$
LVD operating current	$I_{\text{LVD}}$ Notes 1, 7				0.08		$\mu\text{A}$
Self programming operating current	$I_{\text{FSP}}$ Notes 1, 9				2.50	12.20	$\text{mA}$
BGO operating current	$I_{\text{BGO}}$ Notes 1, 8				2.50	12.20	$\text{mA}$
SNOOZE operating current	$I_{\text{SNOZ}}$ Note 1	ADC operation	The mode is performed <sup>Note 10</sup>		0.50	1.10	$\text{mA}$
			The A/D conversion operations are performed, Low voltage mode, $\text{AV}_{\text{REFP}} = \text{V}_{\text{DD}} = 3.0\text{ V}$		1.20	2.04	$\text{mA}$
		CSI/UART operation			0.70	1.54	$\text{mA}$

**Notes** 1. Current flowing to the  $\text{V}_{\text{DD}}$ .

2. When high speed on-chip oscillator and high-speed system clock are stopped.

3. Current flowing only to the real-time clock (RTC) (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either  $I_{\text{DD}1}$  or  $I_{\text{DD}2}$ , and  $I_{\text{RTC}}$ , when the real-time clock operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected,  $I_{\text{FIL}}$  should be added.  $I_{\text{DD}2}$  subsystem clock operation includes the operational current of the real-time clock.4. Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator and the XT1 oscillator). The supply current of the RL78 microcontrollers is the sum of the values of either  $I_{\text{DD}1}$  or  $I_{\text{DD}2}$ , and  $I_{\text{IT}}$ , when the 12-bit interval timer operates in operation mode or HALT mode. When the low-speed on-chip oscillator is selected,  $I_{\text{FIL}}$  should be added.5. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The supply current of the RL78 is the sum of  $I_{\text{DD}1}$ ,  $I_{\text{DD}2}$  or  $I_{\text{DD}3}$  and  $I_{\text{WDT}}$  when the watchdog timer operates.

## 3.4 AC Characteristics

(T<sub>A</sub> =  $-40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq \text{EV}_{\text{DD}0} = \text{EV}_{\text{DD}1} \leq \text{V}_{\text{DD}} \leq 5.5\text{ V}$ ,  $\text{V}_{\text{SS}} = \text{EV}_{\text{SS}0} = \text{EV}_{\text{SS}1} = 0\text{ V}$ )

Items	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Instruction cycle (minimum instruction execution time)	T <sub>cy</sub>	Main system clock (f <sub>MAIN</sub> ) operation	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.03125		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
		Subsystem clock (f <sub>SUB</sub> ) operation		2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	28.5	30.5	31.3	μs
		In the self programming mode	HS (high-speed main) mode	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V	0.03125		1	μs
				2.4 V ≤ V <sub>DD</sub> < 2.7 V	0.0625		1	μs
External system clock frequency	f <sub>EX</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			1.0		20.0	MHz
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			1.0		16.0	MHz
	f <sub>EXS</sub>				32		35	kHz
External system clock input high-level width, low-level width	t <sub>EXH</sub> , t <sub>EXL</sub>	2.7 V ≤ V <sub>DD</sub> ≤ 5.5 V			24			ns
		2.4 V ≤ V <sub>DD</sub> < 2.7 V			30			ns
	t <sub>EXHS</sub> , t <sub>EXLS</sub>				13.7			μs
TI00 to TI07, TI10 to TI17 input high-level width, low-level width	t <sub>TIH</sub> , t <sub>TIL</sub>				1/f <sub>MCK</sub> +10			ns <sup>Note</sup>
TO00 to TO07, TO10 to TO17 output frequency	f <sub>TO</sub>	HS (high-speed main) mode	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			16	MHz	
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V			8	MHz	
			2.4 V ≤ EV <sub>DD0</sub> < 2.7 V			4	MHz	
PCLBUZ0, PCLBUZ1 output frequency	f <sub>PCL</sub>	HS (high-speed main) mode	4.0 V ≤ EV <sub>DD0</sub> ≤ 5.5 V			16	MHz	
			2.7 V ≤ EV <sub>DD0</sub> < 4.0 V			8	MHz	
			2.4 V ≤ EV <sub>DD0</sub> < 2.7 V			4	MHz	
Interrupt input high-level width, low-level width	t <sub>INTH</sub> , t <sub>INTL</sub>	INTP0	2.4 V ≤ V <sub>DD</sub> ≤ 5.5 V	1			μs	
		INTP1 to INTP11	2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	1			μs	
Key interrupt input low-level width	t <sub>KR</sub>	KR0 to KR7	2.4 V ≤ EV <sub>DD0</sub> ≤ 5.5 V	250			ns	
RESET low-level width	t <sub>RSL</sub>				10			μs

**Note** The following conditions are required for low voltage interface when  $\text{EV}_{\text{DD}0} < \text{V}_{\text{DD}}$   
 $2.4\text{ V} \leq \text{EV}_{\text{DD}0} < 2.7\text{ V}$  : MIN. 125 ns

**Remark** f<sub>MCK</sub>: Timer array unit operation clock frequency  
 (Operation clock to be set by the CKSmn0, CKSmn1 bits of timer mode register mn (TMRmn).  
 m: Unit number (m = 0, 1), n: Channel number (n = 0 to 7))

**(6) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq EV_{DD0} = EV_{DD1} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = EV_{SS0} = EV_{SS1} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		Unit
			MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note</sup>	$t_{SIK1}$	$4.0\text{ V} \leq EV_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	88		ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	88		ns
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	220		ns
Slp hold time (from SCKp↓) <sup>Note</sup>	$t_{KSI1}$	$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	38		ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	38		ns
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	38		ns
Delay time from SCKp↑ to SOp output <sup>Note</sup>	$t_{KSO1}$	$4.0\text{ V} \leq EV_{DD0} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$		50	ns
		$2.7\text{ V} \leq EV_{DD0} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		50	ns
		$2.4\text{ V} \leq EV_{DD0} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		50	ns

**Note** When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

**Caution** Select the TTL input buffer for the Slp pin and the N-ch open drain output ( $V_{DD}$  tolerance (for the 20- to 52-pin products)/ $EV_{DD}$  tolerance (for the 64- to 100-pin products)) mode for the SOp pin and SCKp pin by using port input mode register g (PIMg) and port output mode register g (POMg). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

(Remarks are listed on the next page.)



## 3.6.5 Power supply voltage rising slope characteristics

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{SS} = 0$  V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	$S_{VDD}$				54	V/ms

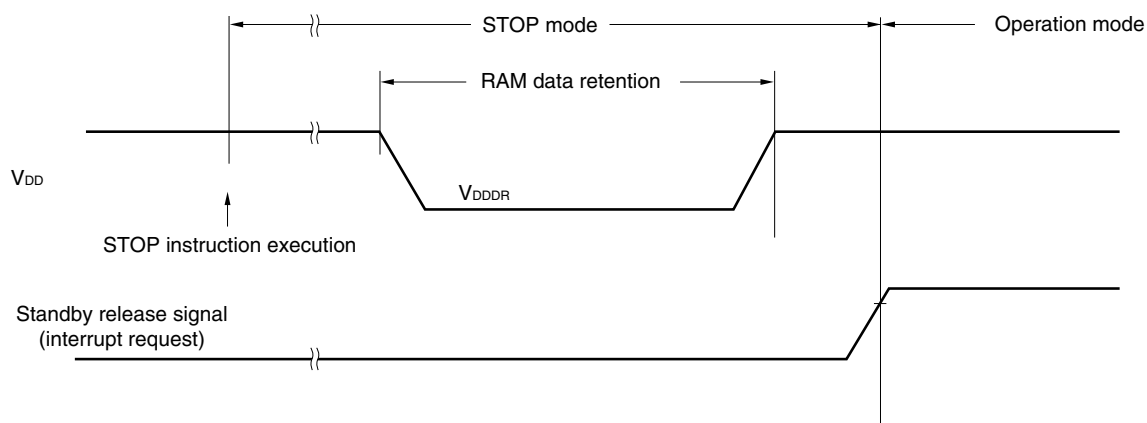
**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until  $V_{DD}$  reaches the operating voltage range shown in 3.4 AC Characteristics.

## 3.7 RAM Data Retention Characteristics

 $(T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{SS} = 0$  V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	$V_{DDDR}$		1.44 <sup>Note</sup>		5.5	V

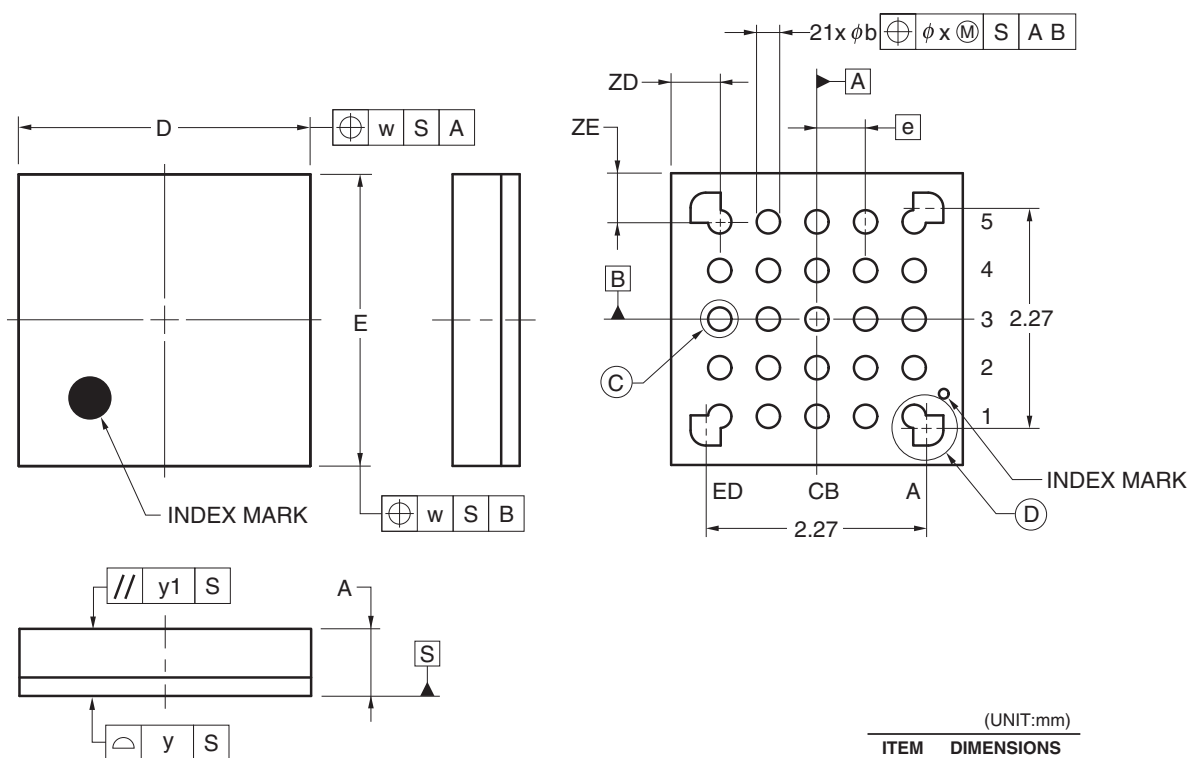
**Note** This depends on the POR detection voltage. For a falling voltage, data in RAM are retained until the voltage reaches the level that triggers a POR reset but not once it reaches the level at which a POR reset is generated.



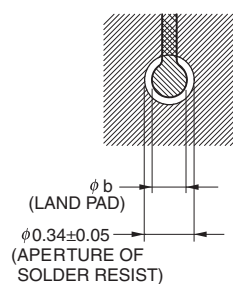
## 4.3 25-pin Products

R5F1008AALA, R5F1008CALA, R5F1008DALA, R5F1008EALA  
 R5F1018AALA, R5F1018CALA, R5F1018DALA, R5F1018EALA  
 R5F1008AGLA, R5F1008CGLA, R5F1008DGLA, R5F1008EGLA

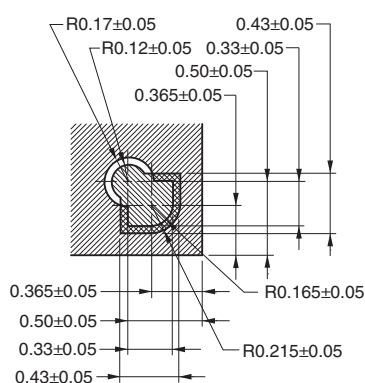
JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-WFLGA25-3x3-0.50	PWLG0025KA-A	P25FC-50-2N2-2	0.01



DETAIL OF ③ PART



DETAIL OF ④ PART



(UNIT:mm)

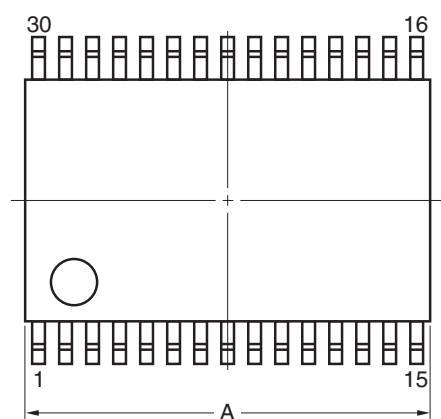
ITEM	DIMENSIONS
D	3.00 ±0.10
E	3.00 ±0.10
w	0.20
e	0.50
A	0.69 ±0.07
b	0.24 ±0.05
x	0.05
y	0.08
y1	0.20
ZD	0.50
ZE	0.50

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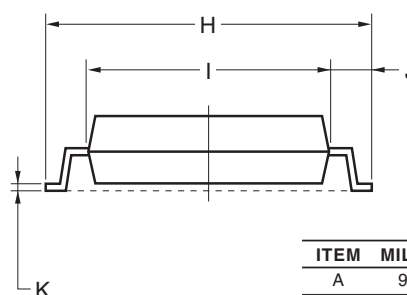
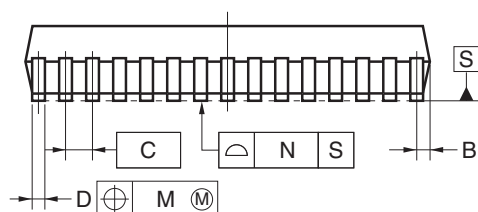
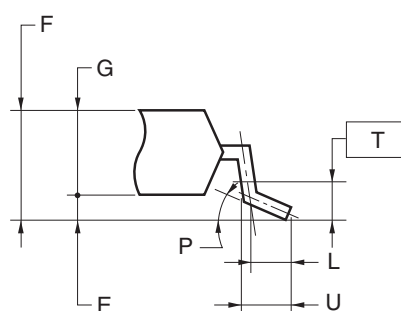
## 4.4 30-pin Products

R5F100AAASP, R5F100ACASP, R5F100ADASP, R5F100AEASP, R5F100AFASP, R5F100AGASP  
 R5F101AAASP, R5F101ACASP, R5F101ADASP, R5F101AEASP, R5F101AFASP, R5F101AGASP  
 R5F100AADSP, R5F100ACDSP, R5F100ADDSP, R5F100AEDSP, R5F100AFDSP, R5F100AGDSP  
 R5F101AADSP, R5F101ACDSP, R5F101ADDSP, R5F101AEDSP, R5F101AFDSP, R5F101AGDSP  
 R5F100AAGSP, R5F100ACGSP, R5F100ADGSP, R5F100AEGSP, R5F100AFGSP, R5F100AGGSP

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LSSOP30-0300-0.65	PLSP0030JB-B	S30MC-65-5A4-3	0.18



detail of lead end

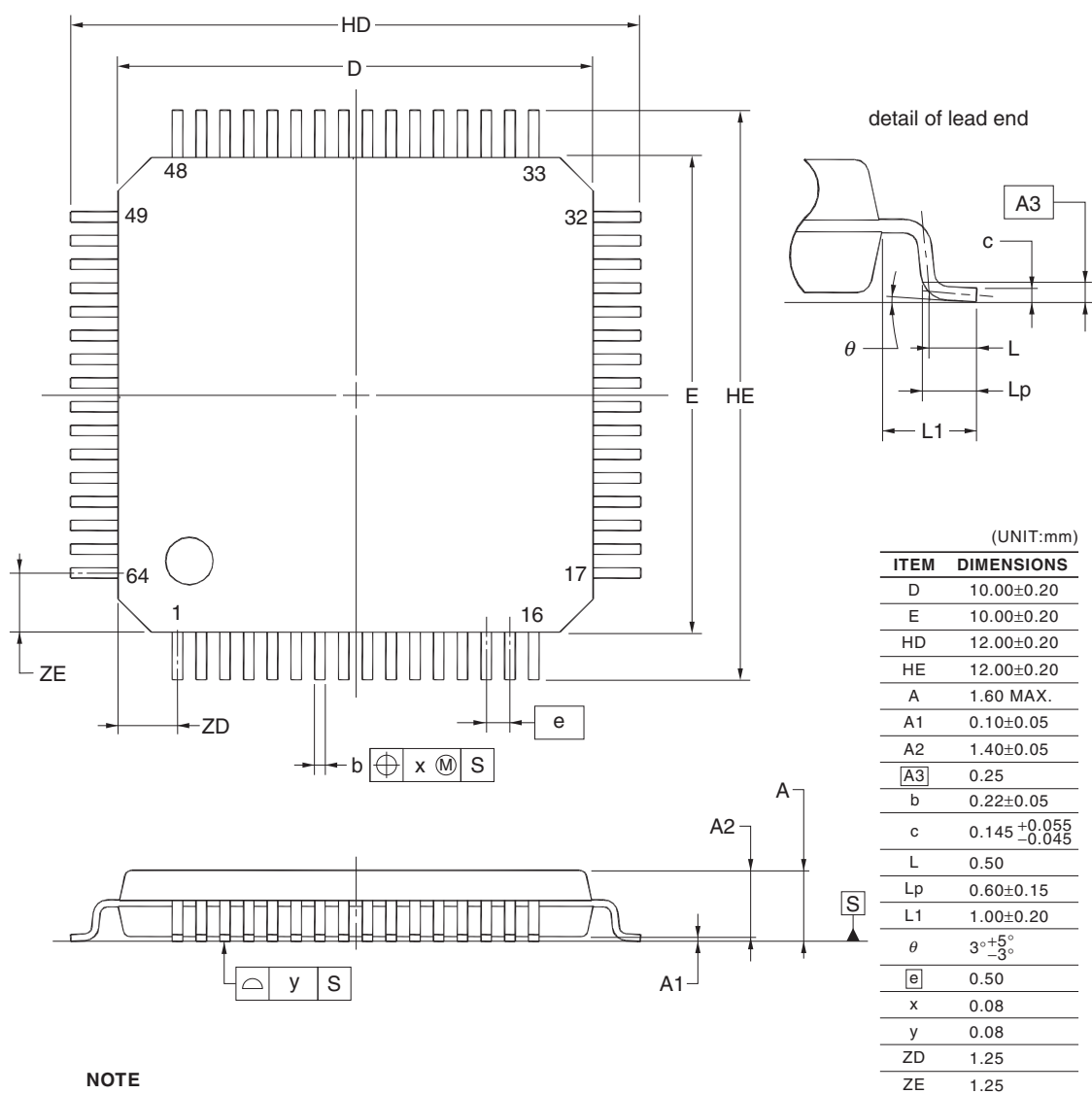
**NOTE**

Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	9.85±0.15
B	0.45 MAX.
C	0.65 (T.P.)
D	0.24 <sup>+0.08</sup> <sub>-0.07</sub>
E	0.1±0.05
F	1.3±0.1
G	1.2
H	8.1±0.2
I	6.1±0.2
J	1.0±0.2
K	0.17±0.03
L	0.5
M	0.13
N	0.10
P	3° <sup>+5°</sup> <sub>-3°</sub>
T	0.25
U	0.6±0.15

R5F100LCAFB, R5F100LDAFB, R5F100LEAFB, R5F100LFAFB, R5F100LGAFB, R5F100LHAFB, R5F100LJAFB,  
 R5F100LKAFB, R5F100LLAFB  
 R5F101LCAFB, R5F101LDAFB, R5F101LEAFB, R5F101LFAFB, R5F101LGAFB, R5F101LHAFB,  
 R5F101LJAFB, R5F101LKAFB, R5F101LLAFB  
 R5F100LCDFB, R5F100LDDFB, R5F100LEDFB, R5F100LDFB, R5F100LGDFB, R5F100LHDFB, R5F100LJDFB,  
 R5F100LKDFB, R5F100LLDFB  
 R5F101LCDFB, R5F101LDDFB, R5F101LEDFB, R5F101LDFB, R5F101LGDFB, R5F101LHDFB,  
 R5F101LJDFB, R5F101LKDFB, R5F101LLDFB  
 R5F100LCGFB, R5F100LDGFB, R5F100LEGFB, R5F100LFGFB, R5F100LGGFB, R5F100LHGFB,  
 R5F100LJGFB

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LFQFP64-10x10-0.50	PLQP0064KF-A	P64GB-50-UEU-2	0.35



#### NOTE

Each lead centerline is located within 0.08 mm of its true position at maximum material condition.

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<http://www.renesas.com>

Refer to "http://www.renesas.com/" for the latest and detailed information.

#### California Eastern Laboratories, Inc.

4590 Patrick Henry Drive, Santa Clara, California 95054-1817, U.S.A.  
Tel: +1-408-919-2500, Fax: +1-408-988-0279

#### Renesas Electronics Europe Limited

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K  
Tel: +44-1628-585-100, Fax: +44-1628-585-900

#### Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

#### Renesas Electronics (China) Co., Ltd.

Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

#### Renesas Electronics (Shanghai) Co., Ltd.

Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333  
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

#### Renesas Electronics Hong Kong Limited

Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2265-6688, Fax: +852 2886-9022

#### Renesas Electronics Taiwan Co., Ltd.

13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan  
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

#### Renesas Electronics Singapore Pte. Ltd.

80 Bendemeer Road, Unit #06-02, Hyflux Innovation Centre, Singapore 339949  
Tel: +65-6213-0200, Fax: +65-6213-0300

#### Renesas Electronics Malaysia Sdn.Bhd.

Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia  
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

#### Renesas Electronics India Pvt. Ltd.

No.777C, 100 Feet Road, HAL II Stage, Indiranagar, Bangalore, India  
Tel: +91-80-67208700, Fax: +91-80-67208777

#### Renesas Electronics Korea Co., Ltd.

12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea  
Tel: +82-2-558-3737, Fax: +82-2-558-5141